



A Product Line of Diodes Incorporated

DMP21D0UFB

#### 20V P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> Max	<b>I</b> <sub>D</sub> Max @ T <sub>A</sub> = 25°C (Note 4)
	495mΩ @ V <sub>GS</sub> = -4.5V	-0.77A
-20V	690mΩ @ V <sub>GS</sub> = -2.5V	-0.67A
	960mΩ @ V <sub>GS</sub> = -1.8V	-0.57A

## **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance  $(R_{DS(on)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Portable electronics

#### **Features and Benefits**

- Footprint of just 0.6mm<sup>2</sup> thirteen times smaller than SOT23
- Low Gate Threshold Voltage
- Fast Switching Speed
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- ESD Protected Gate 3KV
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

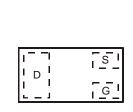
- Case: DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)



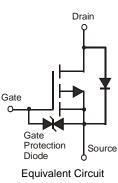


DFN1006-3

Bottom View



Top View Internal Schematic



#### Ordering Information (Note 3)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMP21D0UFB-7B	NG	7	8	10,000

Notes: 1. No purposefully added lead

2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**

DMP21D0UFB-7B



NG = Product Type Marking Code

Top View Bar Denotes Gate and Source Side





# DMP21D0UFB

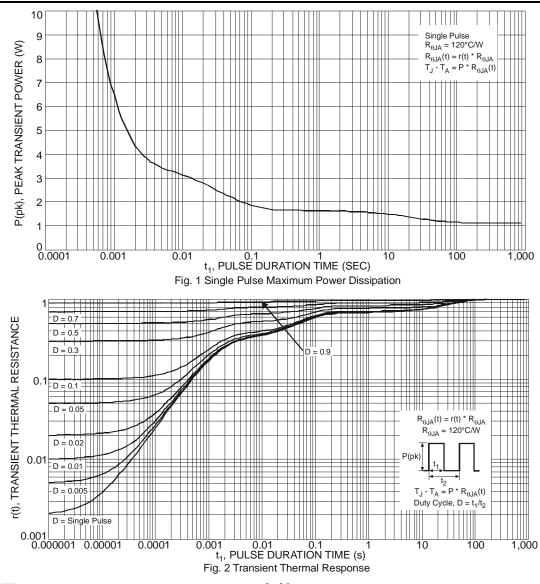
#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage			V <sub>DSS</sub>	-20	V
Gate-Source Voltage			V <sub>GSS</sub>	±8	V
Continuous Drain Current	Steady State	$T_A = 25^{\circ}C$ (Note 4) $T_A = 85^{\circ}C$ (Note 4) $T_A = 25^{\circ}C$ (Note 5)	ID	-0.77 -0.55 -1.17	А
Pulsed Drain Current (Note 6)		I <sub>DM</sub>	-5.0	А	

## Thermal Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	PD	0.43	W
Power Dissipation (Note 5)	PD	0.99	W
Thermal Resistance, Junction to Ambient (Note 4)	R <sub>θJA</sub>	293	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	126	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

#### **Thermal Characteristics**



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DMP21D0UFB

#### Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified Characteristic Symbol Max Unit Min Тур **Test Condition OFF CHARACTERISTICS (Note 7)** Drain-Source Breakdown Voltage 20 V $V_{GS} = 0V, I_D = -250 \mu A$ **BV**<sub>DSS</sub> -Zero Gate Voltage Drain Current TJ = 25°C $V_{DS} = -20V, V_{GS} = 0V$ IDSS \_ -1 μΑ Gate-Source Leakage Igss --±10 μΑ $V_{GS} = \pm 8V, V_{DS} = 0V$ ON CHARACTERISTICS (Note 7) $V_{DS} = V_{GS}, I_D = -250 \mu A$ V Gate Threshold Voltage -0.7 VGS(th) -495 $V_{GS} = -4.5V, I_D = -400mA$ V<sub>GS</sub> = -2.5V, I<sub>D</sub> = -300mA Static Drain-Source On-Resistance 690 mΩ RDS (ON) 960 $V_{GS} = -1.8V, I_D = -100mA$ Forward Transfer Admittance 50 $V_{DS} = -3V, I_{D} = -300 \text{mA}$ |Y<sub>fs</sub>| -mS **Diode Forward Voltage** --1.2 V $V_{GS} = 0V, I_{S} = -300 \text{mA}$ VSD -DYNAMIC CHARACTERISTICS Input Capacitance -80 pF Ciss $V_{DS} = -10V, V_{GS} = 0V,$ Coss **Output Capacitance** -15.5 pF f = 1.0MHz10.4 -Reverse Transfer Capacitance Crss pF -599.2 -Gate Resistance Rg Ω $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ 1.54 Total Gate Charge Qg nC $V_{GS} = -8V, V_{DS} = -15V, I_{D} = -1A$ 0.91 Total Gate Charge Qa -nC $V_{GS} = -4.5V, V_{DS} = -15V,$ Gate-Source Charge 0.14 Qgs nC I<sub>D</sub> = -1A Gate-Drain Charge 0.24 nC Q<sub>gd</sub> --6.7 Turn-On Delay Time t<sub>D(on)</sub> -ns 9.2 Turn-On Rise Time tr -ns $V_{DS} = -10V, -I_{D} = 1A$ 49.2 Turn-Off Delay Time -- $V_{GS} = -4.5V, R_G = 6\Omega$ t<sub>D(off)</sub> ns Turn-Off Fall Time 34.5 t, ns

Notes:

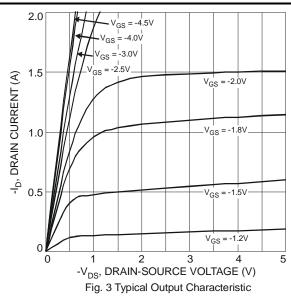
4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

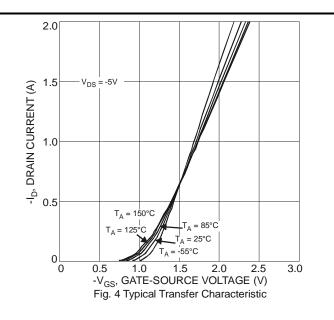
5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate

6. Device mounted on minimum recommended pad layout test board, 10 s pulse duty cycle = 1%.

7. Short duration pulse test used to minimize self-heating effect.

#### **Typical Characteristics**







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T<sub>A</sub> = 150°C

125°C T<sub>A</sub> = 85°C

= 25°C

= -55°C

-I<sub>D</sub>, DRAIN CURRENT (A)

Fig. 6 Typical On-Resistance

1.2

0.8

/<sub>GS</sub> = -2.5V

0

25

= -250mA  $I_D$ 

V<sub>GS</sub> = -5.0V

= -500mA

50

75

= 25°C

0.8

0.6

100

1.0

125 150

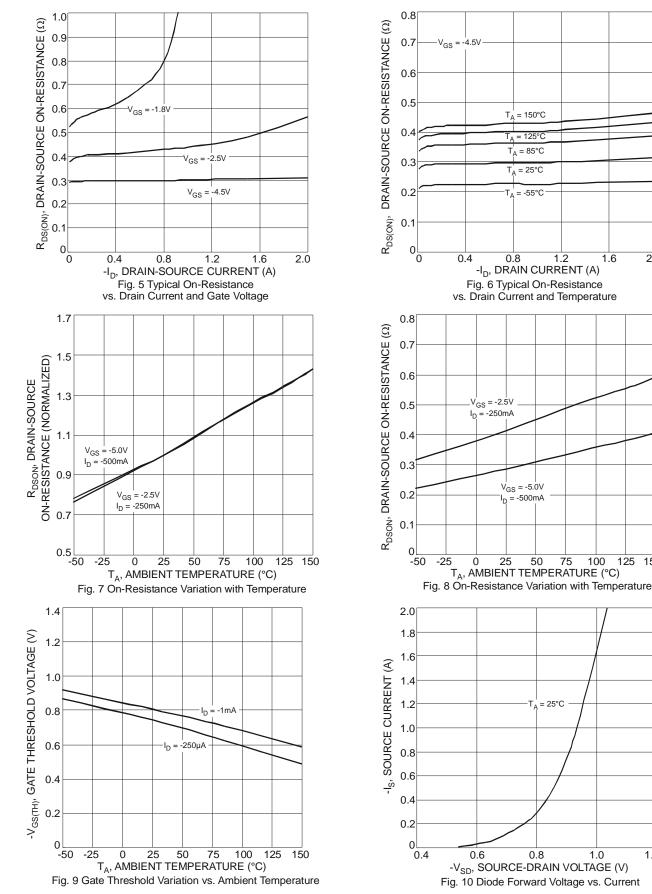
4.5V



DMP21D0UFB

2.0

1.6



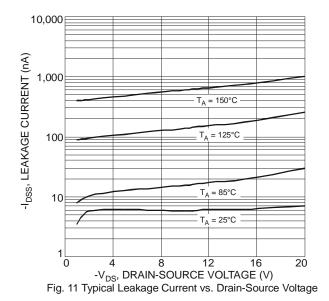
1.2

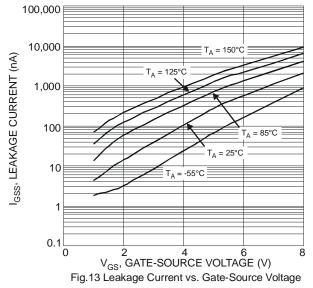


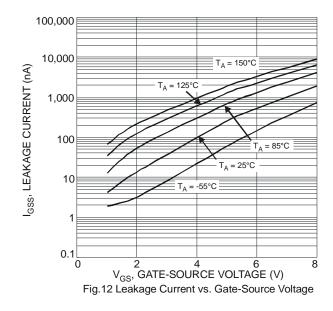
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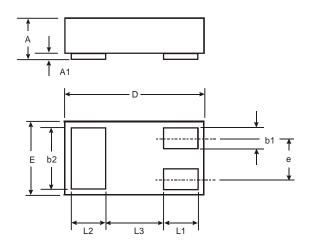
# DMP21D0UFB







# **Package Outline Dimensions**



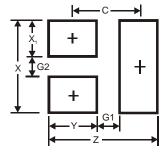
	DFN1006-3			
Dim	Min	Max	Тур	
Α	0.47	0.53	0.50	
A1	0	0.05	0.03	
b1	0.10	0.20	0.15	
b2	0.45	0.55	0.50	
D	0.95	1.075	1.00	
Е	0.55	0.675	0.60	
е		_	0.35	
L1	0.20	0.30	0.25	
L2	0.20	0.30	0.25	
L3	_	_	0.40	
All	All Dimensions in mm			

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## **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
С	0.7

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